

Features

- Trench LV MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

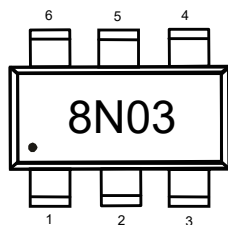
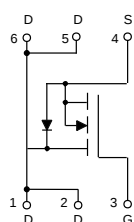
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 78°C/W Junction to Ambient (Note 2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	8	A
		5	
Pulsed Drain Current (Note 3)	I_{DM}	32	A
Total Power Dissipation (Note 4)	P_D	1.6	W

Note:

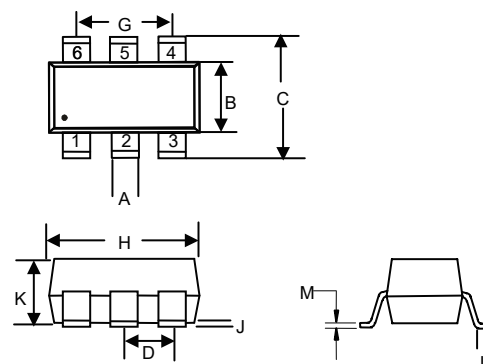
1. Halogen free "Green" products are defined as those which contain <900ppm bromine,
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



N-CHANNEL MOSFET

SOT23-6L



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.059	0.067	1.50	1.70	
C	0.104	0.116	2.65	2.95	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	30			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.0	1.4	3.0	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A		9	14	mΩ
		V _{GS} =4.5V, I _D =8A		11	16	
Gate Resistance	R _G	f=1 MHz, Open drain		2.4		Ω
Forward Tranconductance	g _{FS}	V _{DS} =5V, I _D =8A		21		S
Diode Characteristics						
Continuous Body Diode Current	I _S				8	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =8A			1.2	V
Reverse Recovery Time	t _{rr}	I _F =8A, dI _F /dt=100A/μs		17		ns
Reverse Recovery Charge	Q _{rr}			6		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1MHz		1038		pF
Output Capacitance	C _{oss}			181		
Reverse Transfer Capacitance	C _{rss}			157		
Total Gate Charge	Q _g	V _{DS} =15V, V _{GS} =10V, I _D =8A		22.2		nC
Gate-Source Charge	Q _{gs}			3.1		
Gate-Drain Charge	Q _{gd}			5.3		
Turn-On Delay Time	t _{d(on)}	V _{DD} =25V, V _{GS} =10V, R _{GEN} =2.2Ω, I _D = 1A		8		ns
Turn-On Rise Time	t _r			17		
Turn-Off Delay Time	t _{d(off)}			24		
Turn-Off Fall Time	t _f			22		

Curve Characteristics

Fig.1 - Typical Output Characteristics

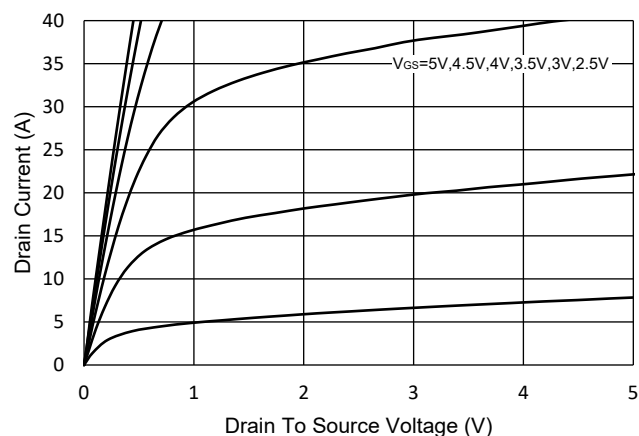


Fig.2 - Transfer Characteristic

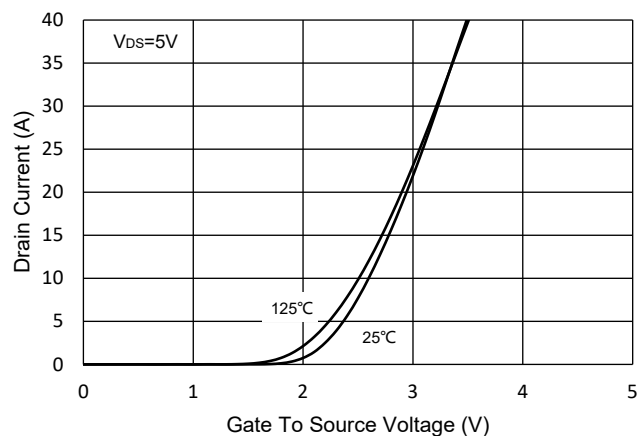


Fig. 3 - $R_{DS(ON)} - V_{GS}$

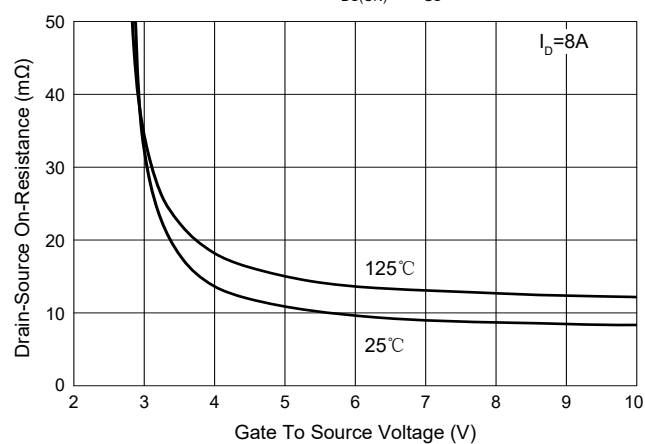


Fig.4 - $R_{DS(ON)} - I_D$

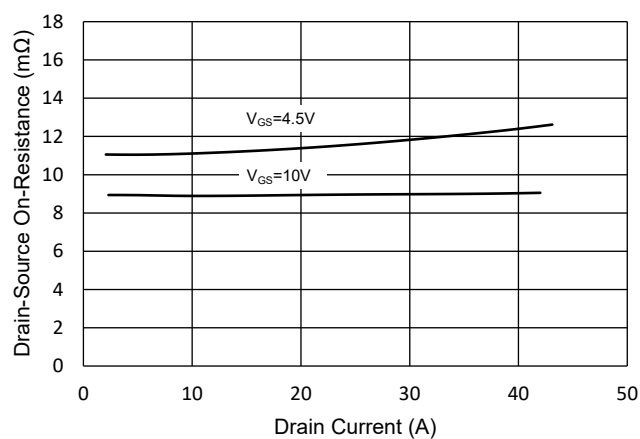


Fig.5 - Capacitance Characteristics

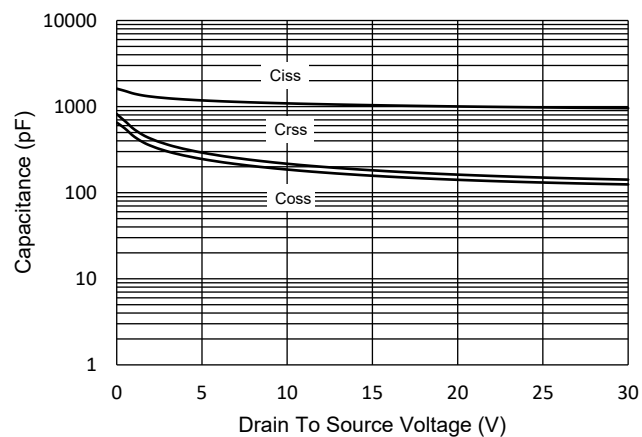
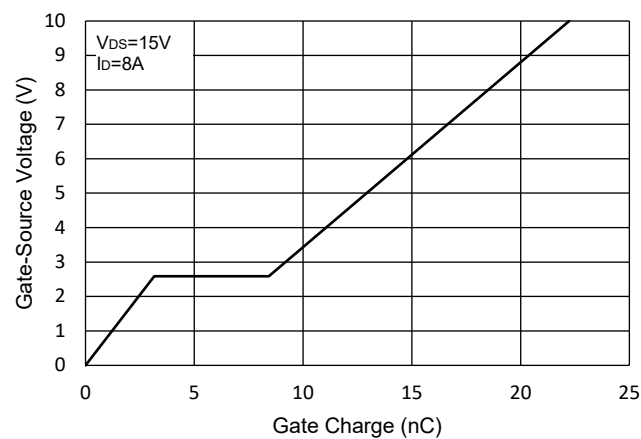


Fig.6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

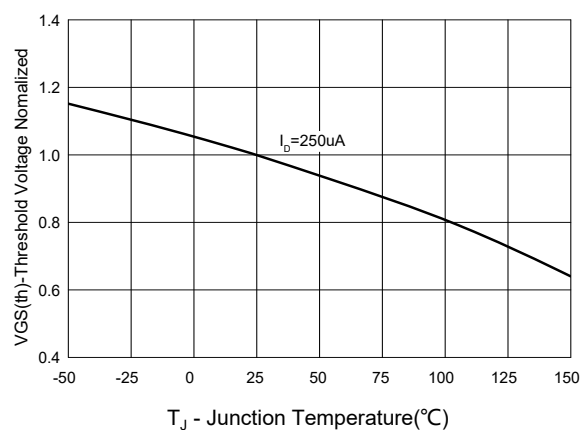


Fig.8 - Normalized On Resistance Characteristics

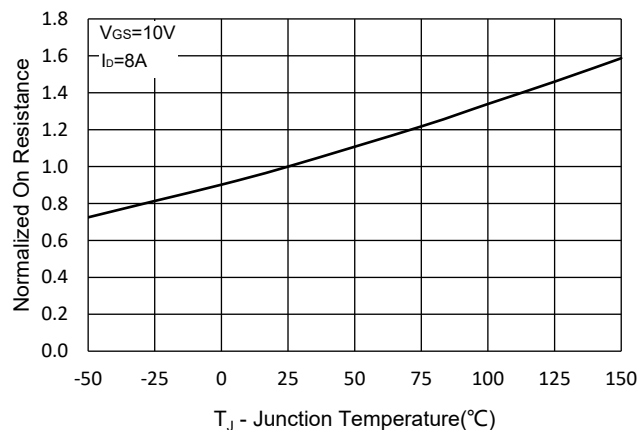


Fig.9 - $I_S - V_{SD}$

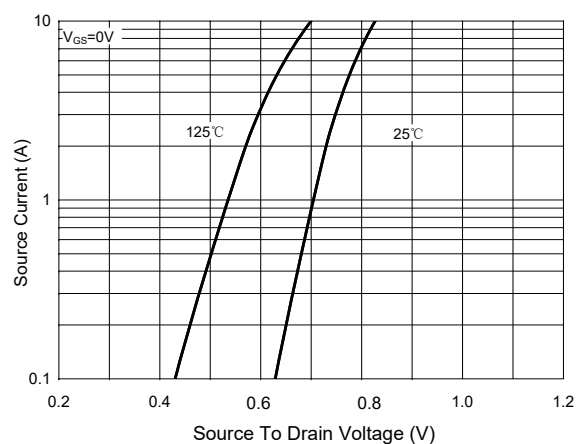


Fig.10 - Drain Current

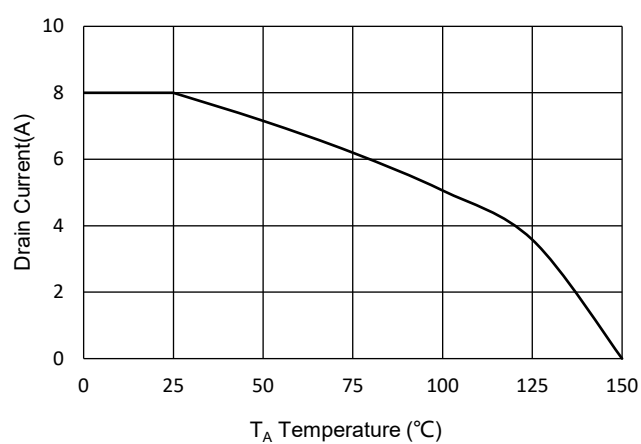
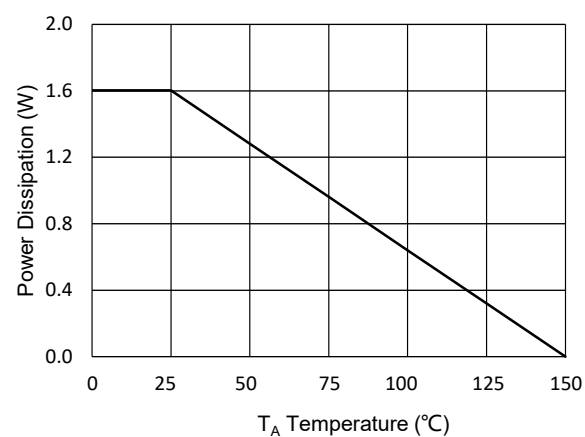
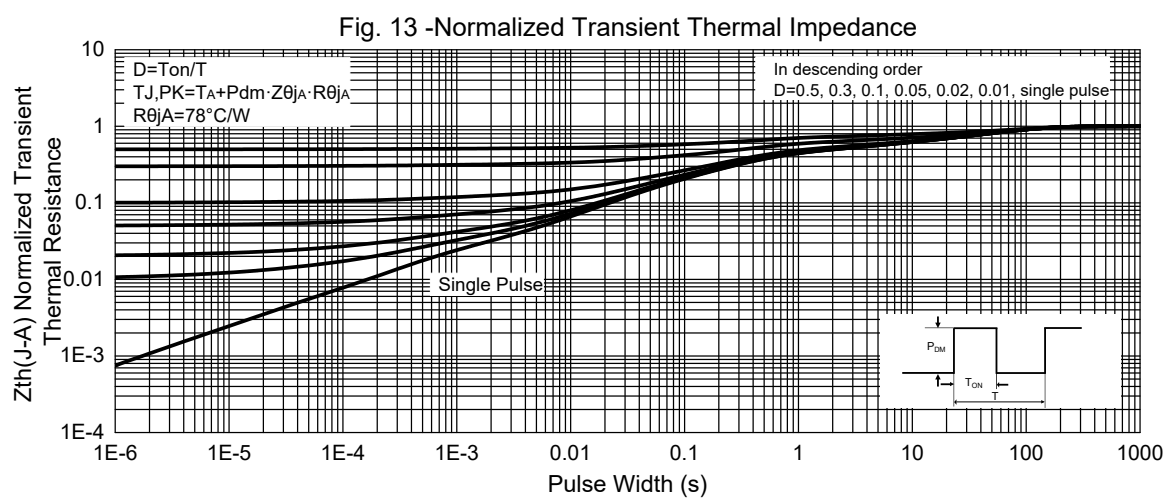
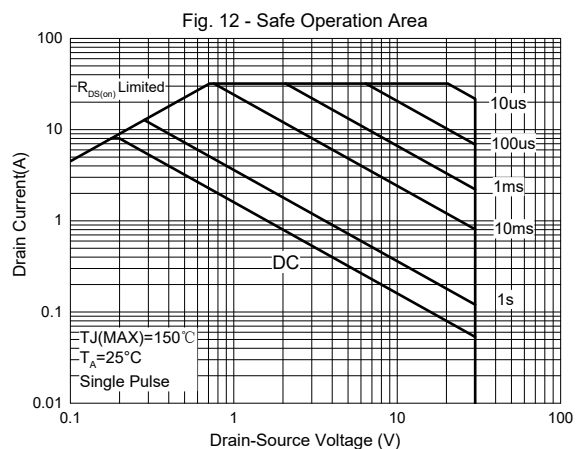


Fig.11 - PD Dissipation



Curve Characteristics



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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